NSN 5962-01-050-9415

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View Online at https://aerobasegroup.com/nsn/5962-01-050-9415

Body Length:

Between 0.370 inches and 0.395 inches

Body Width:

Between 0.245 inches and 0.275 inches

Body Height:

Between 0.040 inches and 0.070 inches

Maximum Power Dissipation Rating:

400.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Hermetically sealed and monolithic and positive outputs and w/buffered output and programmable and programmed and w/storage and

w/enable and w/disable and bipolar and w/open collector and w/decoded output

Inclosure Material:

Ceramic and glass

Inclosure Configuration:

Flat pack

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

6 input

Voltage Rating And Type Per Characteristic:

5.5 volts power source

Time Rating Per Chacteristic:

50.00 nanoseconds propagation delay time, low to high level output and 50.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Prom

Memory Capacity:

Unknown

Precious Material And Location:

Terminals gold

Precious Material:

Gold

Test Data Document:

35351-151471 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

16 flat leads

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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